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High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Application

- Battery charger

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability.

Thanks to an increased intermediate layer, it has an intrinsic ruggedness which enables the transistor to withstand a high collector current level during breakdown condition, without using the transil protection usually necessary in typical converters for lamp ballast.

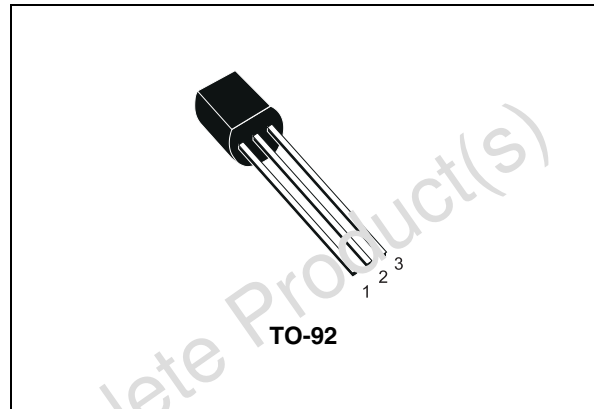


Figure 1. Internal schematic diagram

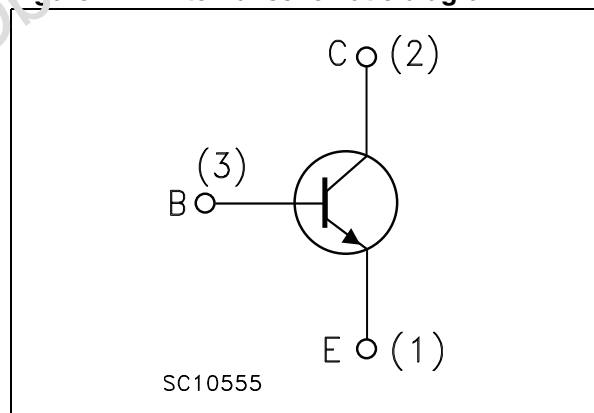


Table 1. Device summary

Order code	Marking	Package	Packaging
STX1F10	X1F10	TO-92	Box

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage ($V_{BE} = 0$)	980	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	15	V
I_C	Collector current	1.5	A
I_{CM}	Collector peak current ($t_P < 5$ ms)	3	A
I_B	Base current	0.5	A
I_{BM}	Base peak current ($t_P < 5$ ms)	1	A
P_{tot}	Total dissipation at $T_C = 25$ °C	2.8	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Thermal resistance junction-case max	44.6	°C/W

2 Electrical characteristics

($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current ($V_{\text{BE}} = 0$)	$V_{\text{CE}} = 980 \text{ V}$ $V_{\text{CE}} = 980 \text{ V}; T_{\text{C}} = 125^{\circ}\text{C}$			50 0.5	μA mA
I_{CEO}	Collector cut-off current ($I_{\text{B}} = 0$)	$V_{\text{CE}} = 400 \text{ V}$			250	μA
$V_{(\text{BR})\text{EBO}}$	Emitter-base breakdown voltage ($I_{\text{C}} = 0$)	$I_{\text{E}} = 1 \text{ mA}$	15			V
$V_{\text{CEO(sus)}}^{(1)}$	Collector-emitter sustaining voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = 10 \text{ mA}$	400			V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 0.3 \text{ A}$ $I_{\text{B}} = 60 \text{ mA}$ $I_{\text{C}} = 1 \text{ A}$ $I_{\text{B}} = 0.2 \text{ A}$		0.15 0.3	0.5 1	V V
$V_{\text{BE(sat)}}^{(1)}$	Base-emitter saturation voltage	$I_{\text{C}} = 1 \text{ A}$ $I_{\text{B}} = 0.2 \text{ A}$		1.1	1.5	V
h_{FE}	DC current gain	$I_{\text{C}} = 500 \mu\text{A}$ $V_{\text{CE}} = 2 \text{ V}$ $I_{\text{C}} = 0.45 \text{ A}$ $V_{\text{CE}} = 5 \text{ V}$ $I_{\text{C}} = 1 \text{ A}$ $V_{\text{CE}} = 5 \text{ V}$	15 30 14	40 20	61 28	
t_{s} t_{f}	Resistive load Storage time Fall time	$V_{\text{CC}} = 125 \text{ V}$ $I_{\text{C}} = 1 \text{ A}$ $I_{\text{B(on)}} = -I_{\text{B(off)}} = 200 \text{ mA}$ $t_{\text{p}} = 300 \mu\text{s}$ $V_{\text{BE(off)}} = -5 \text{ V}$		2.5 350		μs ns

1. Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$.

2.1 Typical characteristic

Figure 2. Safe operating area

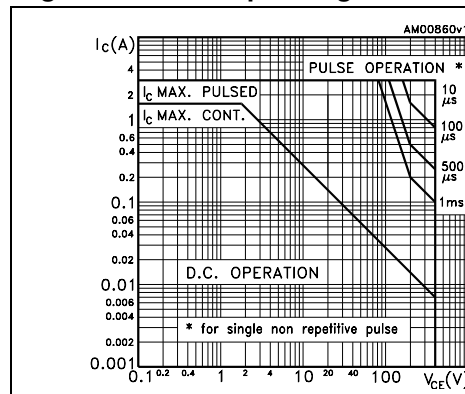


Figure 3. Derating curve

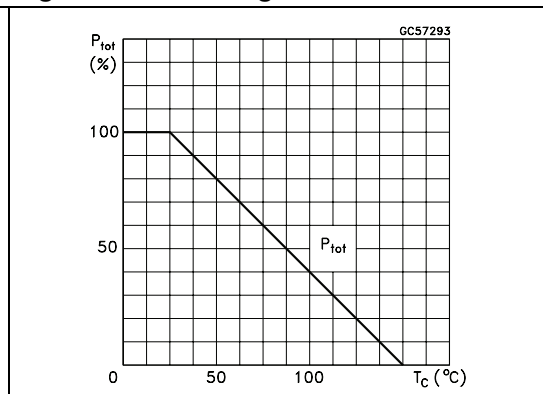


Figure 4. Output characteristics

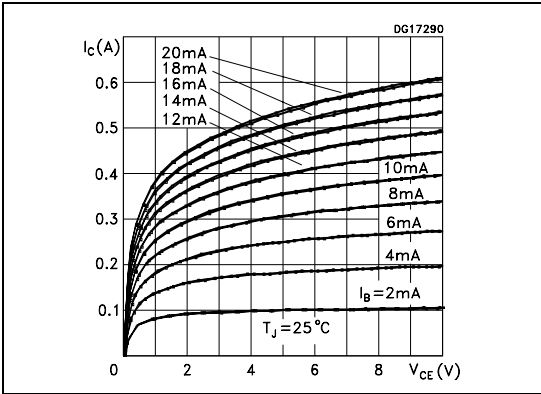


Figure 5. Reverse biased safe operating area

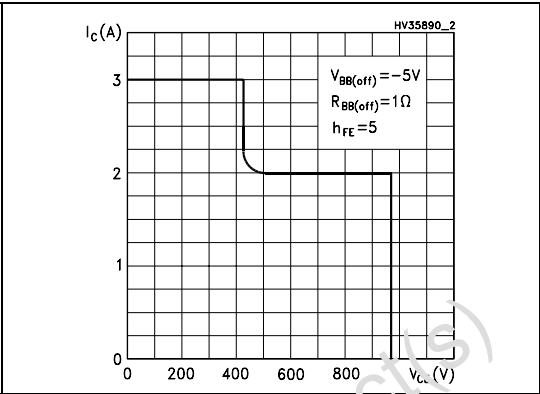


Figure 6. DC current gain ($V_{CE} = 3\text{ V}$)

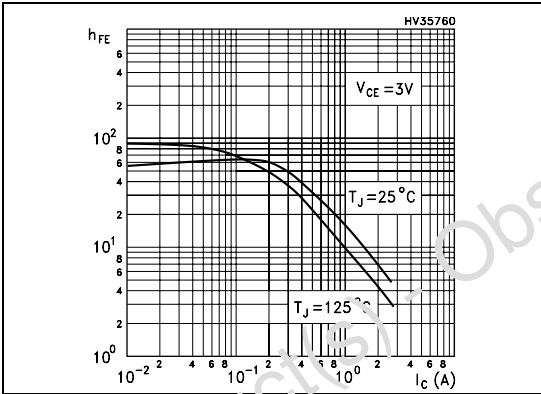


Figure 7. DC current gain ($V_{CE} = 5\text{ V}$)

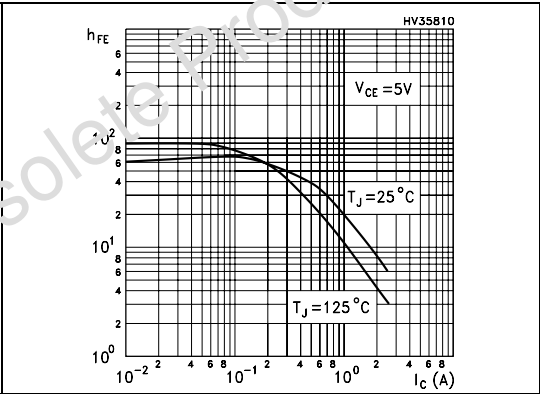


Figure 8. Base-emitter saturation voltage

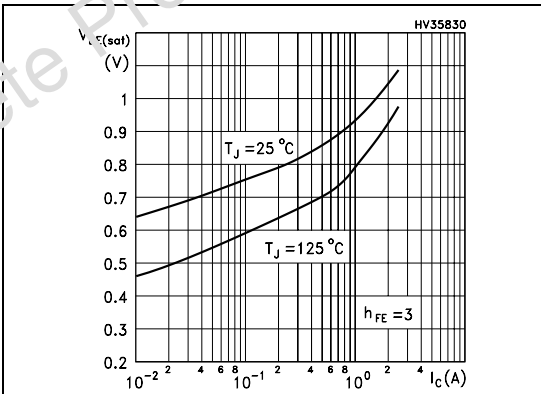


Figure 9. Collector-emitter saturation voltage

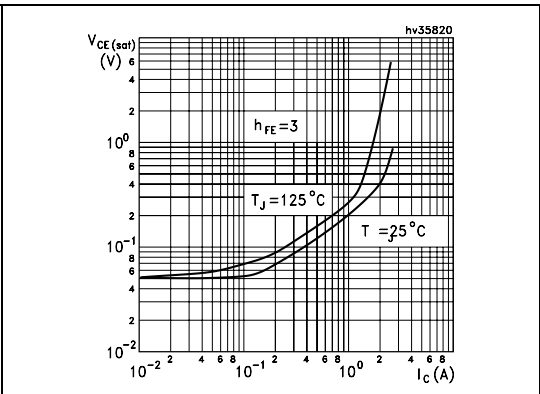


Figure 10. Resistive load switching time (turn-on, $h_{FE} = 5$)

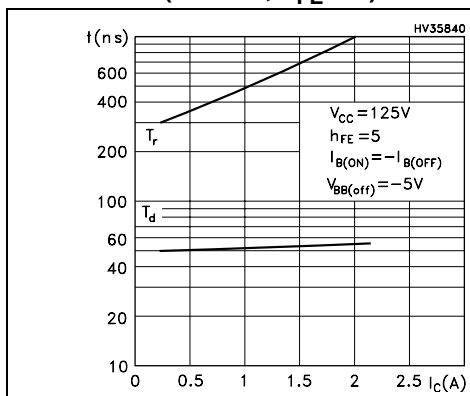


Figure 11. Resistive load switching time (turn-on, $h_{FE} = 10$)

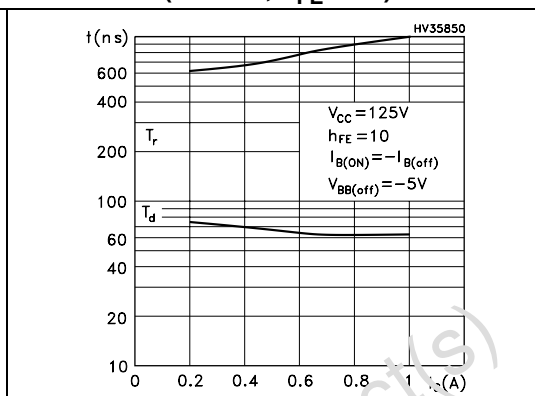


Figure 12. Resistive load switching time (turn-off, $h_{FE} = 5$)

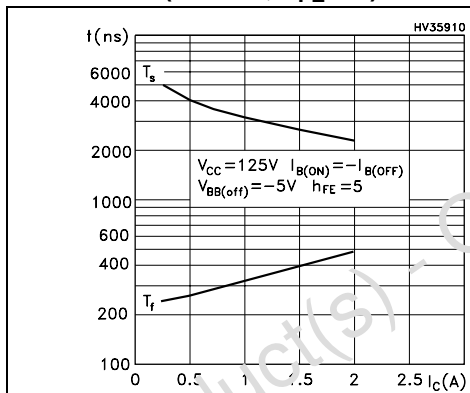
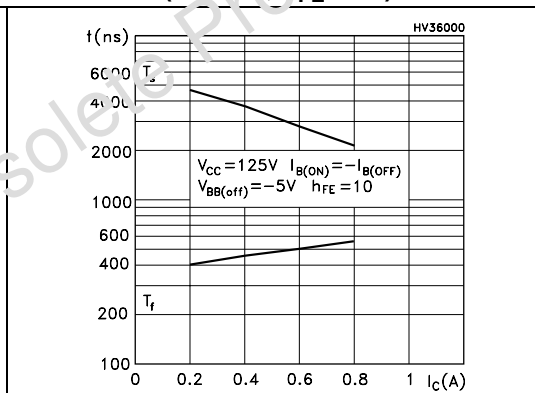
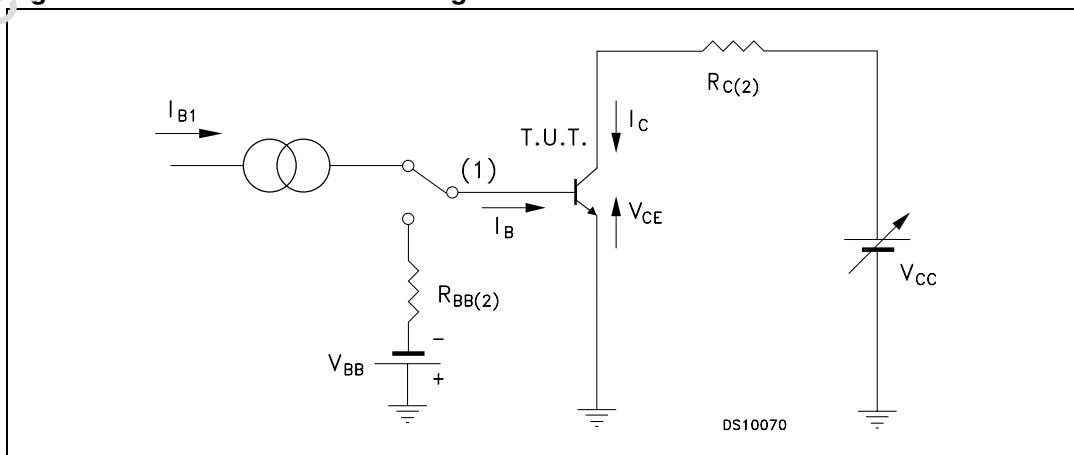


Figure 13. Resistive load switching time (turn-off, $h_{FE} = 10$)



2.2 Test circuits

Figure 14. Resistive load switching test circuit



1. Fast electronic switch
2. Non-inductive resistor

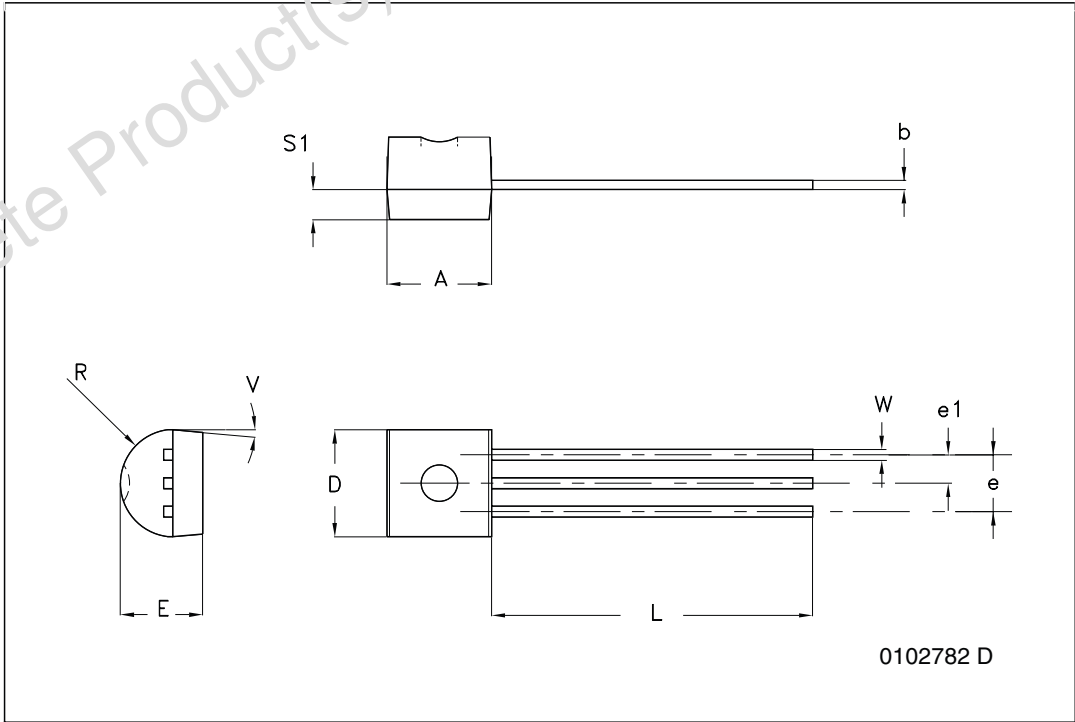
3 Package mechanical data

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Obsolete Product(s) - Obsolete Product(s)

TO-92 bulk shipment mechanical data

DIM.	mm.		
	MIN.	TYP	MAX.
A	4.32		4.95
b	0.36		0.51
D	4.45		4.95
E	3.30		3.94
e	2.41		2.67
e1	1.14		1.40
L	12.70		15.49
R	2.16		2.41
S1	0.92		1.52
W	0.41		0.56
V		5°	



4 Revision history

Table 5. Document revision history

Date	Revision	Changes
18-Jun-2009	1	Initial release.

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